

## Nch 800V 3A Power MOSFET

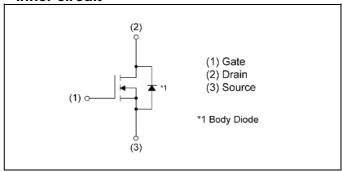
V <sub>DSS</sub>	800V
R <sub>DS(on)</sub> (Max.)	1.8Ω
I <sub>D</sub>	±3A
P <sub>D</sub>	36W

# ● Package TO-220FM

## Features

- 1) Low on-resistance
- 2) Fast switching
- 3) Parallel use is easy
- 4) Pb-free plating ; RoHS compliant

## •Inner circuit



## Application

Switching applications

## Marking specification

Marking	R8003KNX
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# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V <sub>DSS</sub>	800	V
Continuous drain current		I <sub>D</sub> *1	±3	Α
Pulsed drain current		I <sub>DP</sub> *2	±9	Α
Cata Sauma valtara	static	.,	±20	V
Gate - Source voltage	AC(f>1Hz)	$V_{GSS}$	±30	V
Avalanche current, single pulse	·	I <sub>AS</sub>	0.6	Α
Avalanche energy, single pulse	E <sub>AS</sub> *3	19	mJ	
Power dissipation (T <sub>c</sub> = 25°C)	P <sub>D</sub>	36	W	
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and storage temperature	ature range	T <sub>stg</sub>	-55 to +150	°C

## Thermal characteristics

Downwortow	Cymah al	Values			l le:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>th(j-c)</sub> *4	-	-	3.4	°C/W
Thermal resistance, junction - ambient	R <sub>th(j-a)</sub>	-	-	75	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# ● Static characteristics (T<sub>a</sub> = 25°C)

Parameter	Cymabal	Canditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = 1mA$	800	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 800V, V <sub>GS</sub> = 0V	1	-	100	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	ı	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 2mA$	2.5	3.5	4.5	V
Static drain - source on - state resistance	R <sub>DS(on)</sub> *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 1.5A	-	1.5	1.8	Ω

# ● Dynamic characteristics (T<sub>a</sub> = 25°C)

Darramatar	Cymah al	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Urill	
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	5	-	Ω	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, VDS = 100V	-	300	-		
Output capacitance	C <sub>oss</sub>	f = 1MHz	-	25	-		
Effective output capacitance energy related	C <sub>o(er)</sub> *6	V <sub>GS</sub> = 0V	-	5	-	pF	
Effective output capacitance time related	C <sub>o(tr)</sub> *7	V <sub>DS</sub> = 0V to 400V	-	20	-		
Turn - on delay time	t <sub>d(on)</sub> *5	V <sub>DD</sub> ≈ 400V, V <sub>GS</sub> = 10V	-	15	-		
Rise time	<b>t</b> <sub>r</sub> *5	I <sub>D</sub> = 1.5A	-	15	-	20	
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L \simeq 267\Omega$	-	45	-	ns	
Fall time	t <sub>f</sub> *5	$R_G = 10\Omega$	-	65	-		

# ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Darameter	Cumb al	Conditions	Values			Unit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Offic
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≃ 400V	-	11.5	1	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 3A	-	2.5	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 10V	-	5	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> ≈ 400V, I <sub>D</sub> = 3A	-	5.6	-	V

## ●Body diode characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Daramatar	Cumbal	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Urill	
Source current	I <sub>S</sub> *1	T <sub>C</sub> = 25°C	1	1	3	Α	
Pulsed source current	l <sub>SP</sub> *2	1C - 23 C	-	-	9	Α	
Source-Drain voltage	V <sub>SD</sub> *5	$V_{GS} = 0V, I_{S} = 3A$	-	-	1.5	٧	
Reverse recovery time	t <sub>rr</sub> *5		-	230	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *5	I <sub>S</sub> = 3A di/dt = 100A/μs	-	1600	-	μC	
Peak reverse recovery current	<sub>rr</sub> *5	•	-	14	-	Α	

<sup>\*1</sup> Limited only by maximum channel temperature allowed

<sup>\*2</sup> Pw ≤ 10µs, Duty cycle ≤ 1%

<sup>\*3</sup> L  $\stackrel{.}{=}$  100mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , STARTING T<sub>j</sub>=25 $^{\circ}$ C

<sup>\*4</sup> T<sub>C</sub>=25°C

<sup>\*5</sup> Pulsed

 $<sup>^{*}</sup>$ 6 Co(er) is a fixed capacitance that gives the same stored energy as Coss while  $V_{DS}$  is rising from 0 to 50%  $V_{DSS}$ 

<sup>\*7</sup> Co(er) is a fixed capacitance that gives the same charging time as Coss while  $V_{DS}$  is rising from 0 to 50%  $V_{DSS}$ 

Fig.1 Power Dissipation Derating Curve

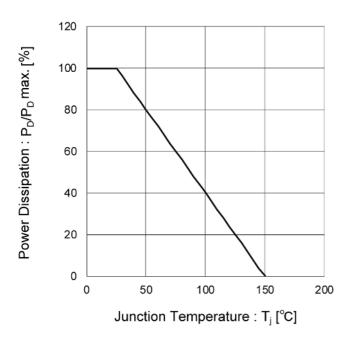


Fig.2 Drain Current Derating Curve

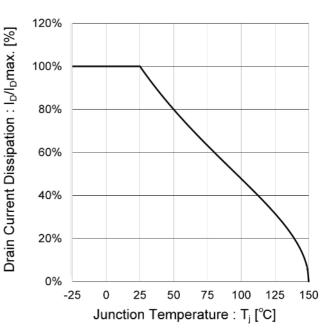


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

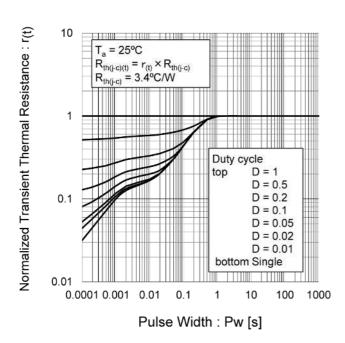
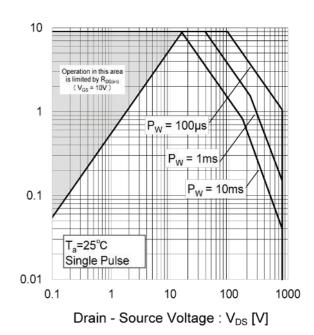


Fig.4 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.5 Avalanche Energy Derating Curve

120 Avalanche Energy: EAS / EAS max [%] 100 80 60 40 20 0 0 25 50 75 100 125 150 175 Junction Temperature : T<sub>j</sub> [°C]

Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

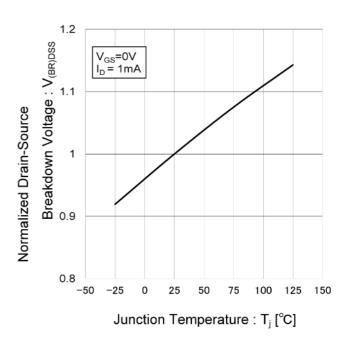
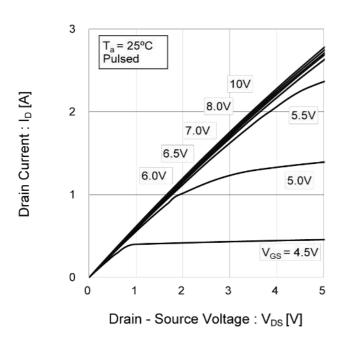


Fig.8 Output Characteristics(II)

Fig.7 Output Characteristics(I))



2

3 10V T<sub>a</sub> = 25°C Pulsed 8.0V 7.0V 6.0V 5.5V 5.0V 1  $V_{GS} = 4.5V$ 0 10 0 20 30 50

Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.9 Gate Threshold Voltage vs. Drain Current

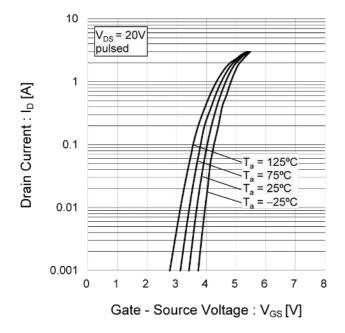


Fig.10 Normalized Gate Threshold Voltage vs. Junction Temperature

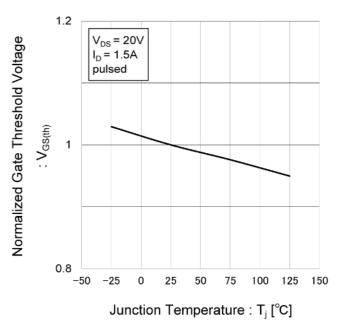


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

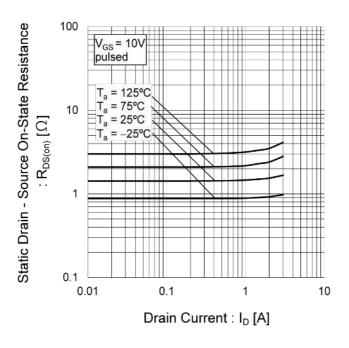
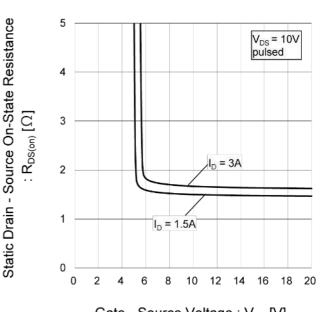
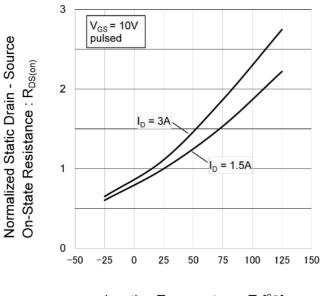


Fig.12 Static Drain - Source On - State Resistance vs. Gate - Source Voltage



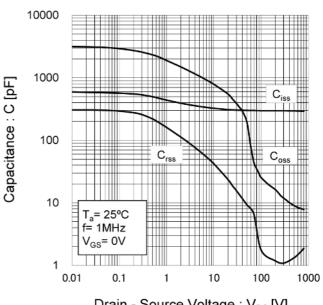
Gate - Source Voltage :  $V_{GS}[V]$ 

Fig.13 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature



Junction Temperature : T<sub>i</sub> [°C]

Fig.14 Capacitances



Drain - Source Voltage: V<sub>DS</sub> [V]

Fig.15 Switching Times

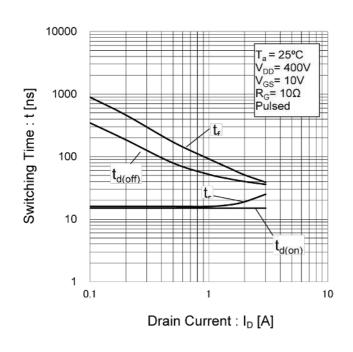
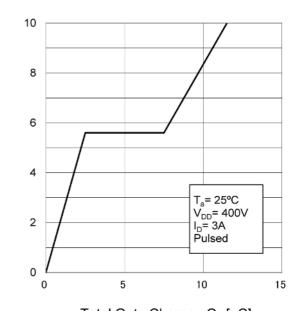


Fig.16 Gate Charge



Total Gate Charge : Qg [nC]

Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.17 Source Current vs. Source - Drain Voltage

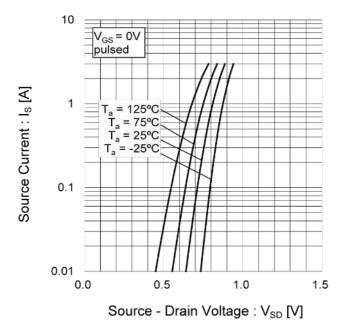
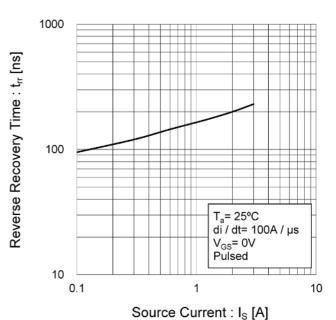


Fig.18 Reverse Recovery Time vs. Source Current





## Measurement circuits

Fig.1-1 Switching time measurement circuit

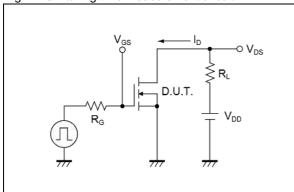


Fig.2-1 Gate charge measurement circuit

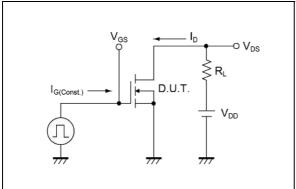


Fig.3-1 Avalanche measurement circuit

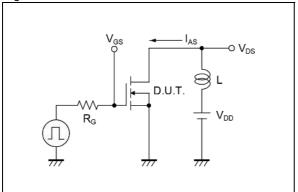


Fig.4-1 trr measurement circuit

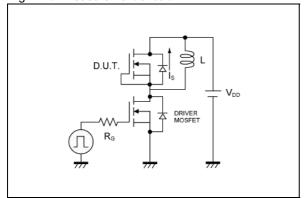


Fig.1-2 Switching waveforms

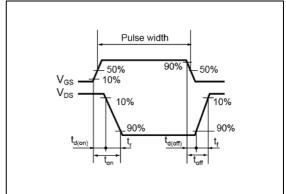


Fig.2-2 Gate charge waveform

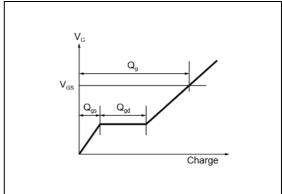


Fig.3-2 Avalanche waveform

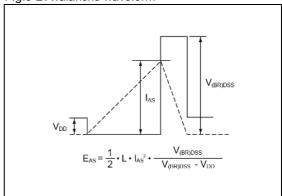
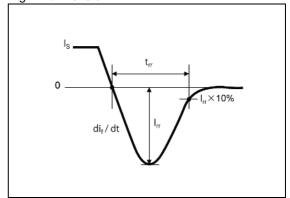
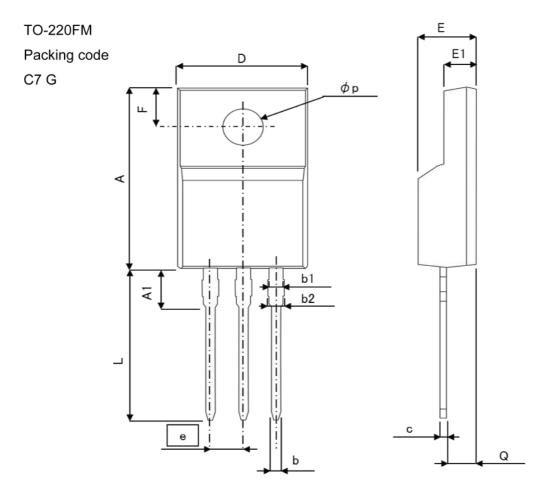


Fig.4-2 trr waveform



## Dimensions



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.67	16.27	0.617	0.641
A1	3.03	3.43	0.119	0.135
b	0.70	0.95	0.028	0.037
b1	1.00	1.40	0.039	0.055
b2	1.10	1.50	0.043	0.059
С	0.45	0.65	0.018	0.026
D	9.90	10.30	0.390	0.406
E	4.60	5.00	0.181	0.197
E1	2.44	2.74	0.096	0.108
е	2.	2.54		00
F	3.10	3.50	0.122	0.138
L	12.6	13.6	0.946	0.535
р	2.98	3.38	0.117	0.133
Q	2.25	3.25	0.089	0.128

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Dimension in mm/inches



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CLASSIV	CLASSII	CLASSⅢ	CLASSⅢ

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  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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